

Lonten N-channel 45V, 85A, 5.5m Ω Power MOSFET

Description	Product Summary
These N-Channel enhancement mode power field	V _{DSS} 45V
effect transistors are using trench DMOS	$R_{DS(on).max}@V_{GS}=10V$ 5.5m Ω
technology. This advanced technology has been	I _D 85A
especially tailored to minimize on-state resistance,	
provide superior switching performance, and with	
stand high energy pulse in the avalanche and	
commutation mode. These devices are well suited	Pin Configuration
for high efficiency fast switching applications.	
Features	
 45V,85A,R_{DS(ON).max}=5.5mΩ@V_{GS}=10V 	
 Improved dv/dt capability 	
Fast switching	
 100% EAS Guaranteed 	
Green device available	TO-251 TO-252 🚰 🛏 🗍
Applications	• \$
Motor Drives	
♦ UPS	N-Channel MOSFET
DC-DC Converter	

Absolute Maximum Ratings T_c = 25°C unless otherwise noted

Parameter	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	45	V	
Continuous drain current ($T_c = 25^{\circ}C$)	1	85	А	
Continuous drain current ($T_c = 100^{\circ}C$)	I _D	59	А	
Pulsed drain current ¹⁾	I _{DM}	340	A	
Gate-Source voltage	V _{GSS}	±20	V	
Avalanche energy ²⁾	E _{AS}	156	mJ	
Power Dissipation ($T_c = 25^{\circ}C$)	PD	100	W	
Storage Temperature Range	T _{STG}	-55 to +150	°C	
Operating Junction Temperature Range	TJ	-55 to +150	°C	

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{ extsf{ heta}JC}$	1.25	°C/W



Package Marking and Ordering Information

Device	Device Package	Marking
LNG045R055	TO-252	LNG045R055
LNH045R055	TO-251	LNH045R055

Electrical Characteristics T_J = 25°C unless otherwise noted

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Static characteristics		1				
Drain-source breakdown voltage	BV _{DSS}	V _{GS} =0 V, I _D =250uA	45			V
Gate threshold voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	0.9		1.8	V
		V_{DS} =45 V, V_{GS} =0 V, T_{J} = 25°C			1	μA
Drain-source leakage current	I _{DSS}	V _{DS} =36 V, V _{GS} =0 V, T _J = 125°C			30	μA
Gate leakage current, Forward	I _{GSSF}	V _{GS} =20 V, V _{DS} =0 V			100	nA
Gate leakage current, Reverse	I _{GSSR}	V _{GS} =-20 V, V _{DS} =0 V			-100	nA
Duain accuracy an atota macintana a	D	V _{GS} =10 V, I _D =30 A		4.3	5.5	mΩ
Drain-source on-state resistance	R _{DS(on)}	V _{GS} =4.5 V, I _D =20 A		5.3	7	mΩ
Forward transconductance	g _{fs}	V _{DS} =5 V , I _D =30A		76		S
Dynamic characteristics						
Input capacitance	C _{iss}			3963		
Output capacitance	C _{oss}	$V_{DS} = 25 V, V_{GS} = 0 V,$		344		pF
Reverse transfer capacitance	C _{rss}	- F = 1MHz		311		
Turn-on delay time	t _{d(on)}			18		
Rise time	tr	$V_{DD}=25V, V_{GS}=10V, I_{D}=30A,$		216.4		- ns
Turn-off delay time	t _{d(off)}	$R_{G}=10\Omega$		209.2		
Fall time	t _f			88		
Gate resistance	R _g	V _{GS} =0V, V _{DS} =0V, F=1MHz		2.1		Ω
Gate charge characteristics						•
Gate to source charge	Q _{gs}			10.8		
Gate to drain charge	Q _{gd}	$V_{DS}=25 V, I_{D}=25A,$		20.2		nC
Gate charge total	Qg	- V _{GS} = 10 V		88.6		1
Drain-Source diode characteristic	s and Maxi	mum Ratings				•
Continuous Source Current	ls				85	Α
Pulsed Source Current	I _{SM}				340	Α
Diode Forward Voltage ³⁾	V _{SD}	V _{GS} =0V, I _S =30A, T _J =25℃			1.2	V
Reverse Recovery Time	t _{rr}			35.6		ns
Reverse Recovery Charge	Qrr	l _s =20A,di/dt=100A/us, T _J =25℃		16		nC

Notes:

1: Repetitive Rating: Pulse width limited by maximum junction temperature.

2: V_DD=25V, V_GS=10V, L=0.5mH, I_{AS}=25A, R_G=25\Omega, Starting T_J=25^{\circ}C.

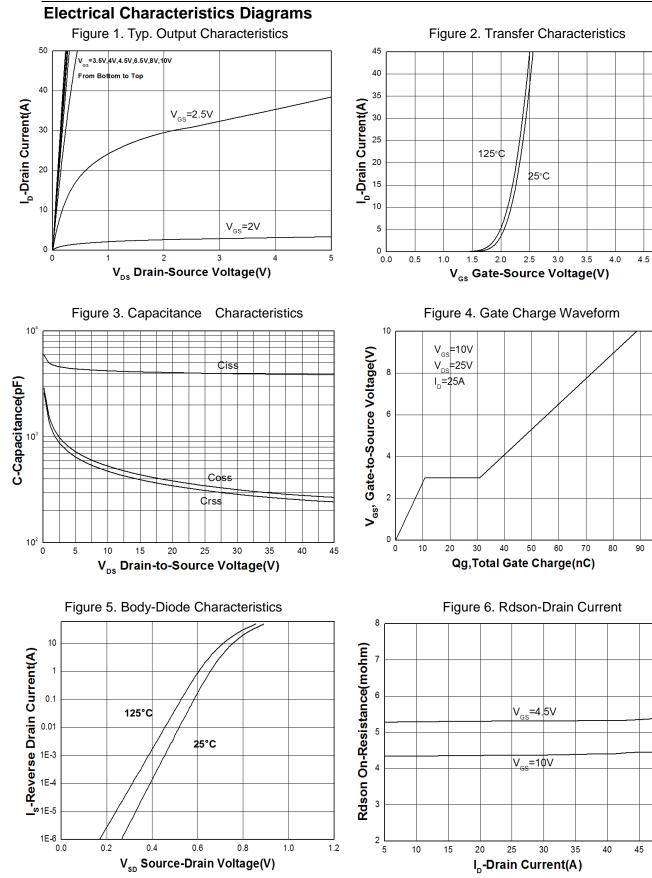
3: Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.



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5.0

100

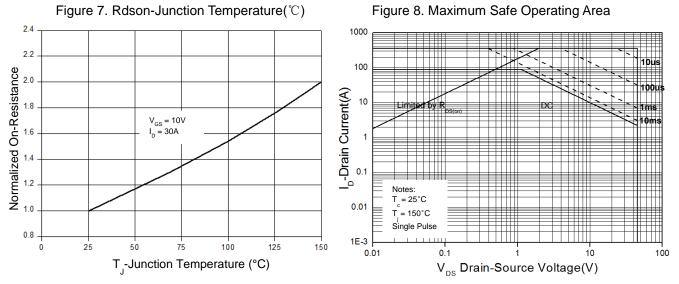


Version 1.0, 2018

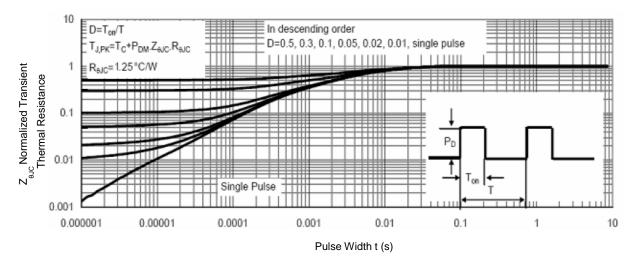
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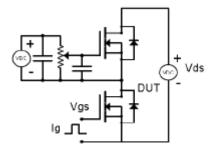






Test Circuit & Waveform

Figure 8. Gate Charge Test Circuit & Waveform



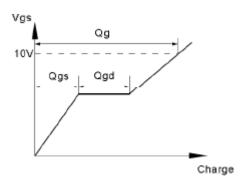


Figure 9. Resistive Switching Test Circuit & Waveforms

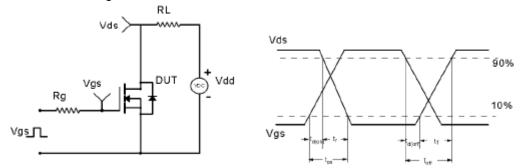
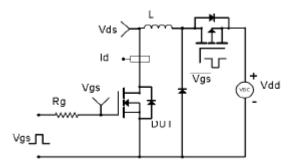


Figure 10. Unclamped Inductive Switching (UIS) Test Circuit & Waveform



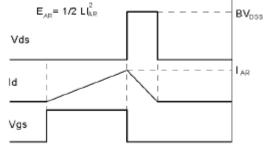
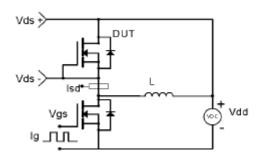
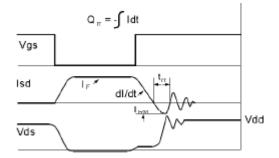


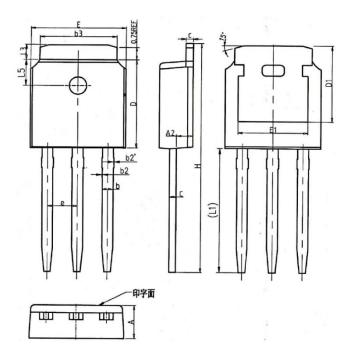
Figure 11. Diode Recovery Circuit & Waveform





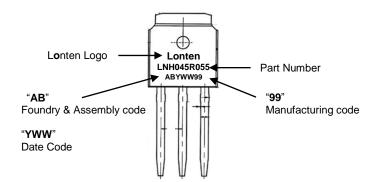


Mechanical Dimensions for TO-251



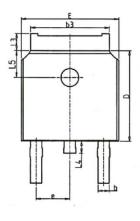
COMMON DIMENSIONS							
SYMBOL	MM			INCH			
STIVIDOL	MIN	NOM	MAX	MIN	NOM	MAX	
А	2.20	2.30	2.38	0.087	0.091	0.094	
A2	0.97	1.07	1.17	0.038	0.042	0.046	
b	0.68	0.78	0.90	0.027	0.031	0.035	
b2	0.00	0.04	0.10	0.000	0.002	0.004	
b2'	0.00	0.04	0.10	0.000	0.002	0.004	
b3	5.20	5.33	5.46	0.205	0.210	0.215	
с	0.43	0.53	0.61	0.017	0.021	0.024	
D	5.98	6.10	6.22	0.235	0.240	0.245	
D1		5.30REF		0.209REF			
E	6.40	6.60	6.73	0.252	0.260	0.265	
E1	4.63	-	-	0.182	-	-	
е	2.286BSC			0.090BSC			
н	16.22	16.52	16.82	0.639	0.650	0.662	
L1	9.15	9.40	9.65	0.360	0.370	0.380	
L3	0.88	1.02	1.28	0.035	0.040	0.050	
L5	1.65	1.80	1.95	0.065	0.071	0.077	

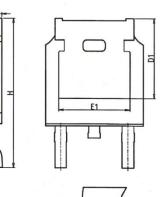
TO-251 Part Marking Information

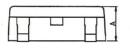


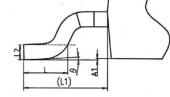


Mechanical Dimensions for TO-252



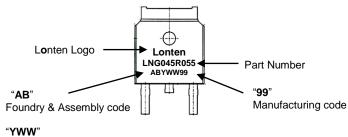






COMMON DIMENSIONS							
SYMBOL	ММ			INCH			
STINDUL	MIN	NOM	MAX	MIN	NOM	MAX	
А	2.20	2.30	2.38	0.087	0.091	0.094	
A1	0.00	-	0.20	0.000	-	0.008	
A2	0.97	1.07	1.17	0.038	0.042	0.046	
b	0.68	0.78	0.90	0.027	0.031	0.035	
b3	5.20	5.33	5.46	0.205	0.210	0.215	
с	0.43	0.53	0.61	0.017	0.021	0.024	
D	5.98	6.10	6.22	0.235	0.240	0.245	
D1		5.30REF	-	0.209REF			
Е	6.40	6.60	6.73	0.252	0.260	0.265	
E1	4.63	-	-	0.182	-	-	
е		2.286BS	С	0.090BSC			
Н	9.40	10.10	10.50	0.370	0.398	0.413	
L	1.38	1.50	1.75	0.054	0.059	0.069	
L1	2.90REF			0.114REF			
L2	0.51BSC			0.020BSC			
L3	0.88	-	1.28	0.035	-	0.050	
L4	0.50	-	1.00	0.020	-	0.039	
L5	1.65	1.80	1.95	0.065	0.071	0.077	
θ	0°	-	8°	0°	-	8°	

TO-252 Part Marking Information



"YWW" Date Code



LNH045R055/LNG045R055

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